

N-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A) ^a	Q _g (Typ.)	
30	0.006 at V _{GS} = 10 V	68	31 nC	
30	0.013 at V $_{GS}$ = 4.5 V	53	31110	

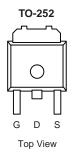
FEATURES

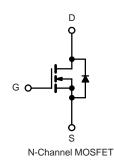
- DT-Trench Power MOSFET
- 100 % R_g Tested
- 100 % Avalanche Tested



APPLICATIONS

- Low-Side Switch for DC/DC Converters
 - Servers
 - POL
 - VRM
- OR-ing





Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	30	V	
Gate-Source Voltage		V_{GS}	± 20	v	
	T _C = 25 °C		68		
Continuous Drain Current (T _{.1} = 150 °C)	T _C = 70 °C	1_	53	7	
Continuous Diam Current (1) = 130 C)	T _A = 25 °C	'D	26 ^{b, c}		
	T _A = 70 °C		21 ^{b, c}		
Pulsed Drain Current		I _{DM}	195	Α	
Continuous Source-Drain Diode Current	T _C = 25 °C	l _a	68		
Continuous Source-Drain Diode Current	T _A = 25 °C	I _S	5 ^{b, c}		
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	65		
Single Pulse Avalanche Energy	L = 0.111111	E _{AS}	113	mJ	
	T _C = 25 °C		75		
Maximum Power Dissipation	T _C = 70 °C	P _D	48	w	
Maximum Fower Dissipation	T _A = 25 °C	' D	4.9 ^{b, c}	VV	
	T _A = 70 °C		3.1 ^{b, c}		
Operating Junction and Storage Temperature Ra	T _J , T _{stg}	- 55 to 150	°C		
Soldering Recommendations (Peak Temperature		260			

THERMAL RESISTANCE RATINGS							
Parameter		Symbol	Typical	Maximum	Unit		
Maximum Junction-to-Ambient	t ≤ 10 s	R _{thJA}	18	23	°C/W		
Maximum Junction-to-Case (Drain)	Steady State	R_{thJC}	1.0	1.5			

- a. Based on T_C = 25 °C. b. Surface Mounted on 1" x 1" FR4 board.
- c. t = 10 s.

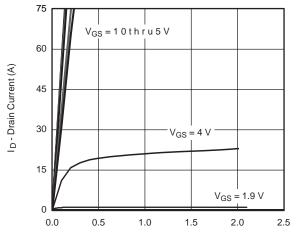


Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	30			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$	I _D = 250 μA		28		m\//0C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	1 _D = 250 μΑ		- 6.6		mV/°C	
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	1.0		3.0	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zara Cata Valtaga Drain Current		V _{DS} = 24 V, V _{GS} = 0 V			1	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 24 V, V _{GS} = 0 V, T _J = 55 °C			10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	68			Α	
		V _{GS} = 10 V, I _D = 20 A			0.0072	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 10 A			0.016		
Forward Transconductance ^a	9 _{fs}	V _{DS} = 10 V, I _D = 20 A		100		S	
Dynamic ^b					'		
Input Capacitance	C _{iss}			1850			
Output Capacitance	C _{oss}	$V_{DS} = 15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$		550		pF	
Reverse Transfer Capacitance	C _{rss}			75			
•	Q _g	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 20 \text{ A}$		72	105	nC	
Total Gate Charge				31	48		
Gate-Source Charge	Q _{gs}	$V_{DS} = 15 \text{ V}, V_{GS} = 4.5 \text{ V}, I_D = 20 \text{ A}$		11			
Gate-Drain Charge	Q _{gd}			10			
Gate Resistance	R _g	f = 1 MHz	0.2	0.8	1.6	Ω	
Turn-On Delay Time	t _{d(on)}			20			
Rise Time	t _r	V_{DD} = 15 V, R_L = 1.5 Ω		6		-	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong 10$ A, $V_{GEN}=10$ V, $R_g=1$ Ω		43			
Fall Time	t _f			7			
Turn-On Delay Time	t _{d(on)}			44		ns	
Rise Time	t _r	V_{DD} = 10 V, R_L = 1 Ω		19		-	
Turn-Off Delay Time	t _{d(off)}	$I_D\cong$ 10 A, V_{GEN} = 4.5 V, R_g = 1 Ω		63			
Fall Time	t _f			31			
Drain-Source Body Diode Characteristi	cs			•			
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C			68	۸	
Pulse Diode Forward Current ^a	I _{SM}				195	Α	
Body Diode Voltage	V_{SD}	I _S = 4 A		0.7	1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			35	55	ns	
Body Diode Reverse Recovery Charge	Q _{rr}	L = 10 A dl/dt = 100 A/up T = 25 °C		25	43	nC	
Reverse Recovery Fall Time	t _a	$I_F = 10 \text{ A}, \text{ dI/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^{\circ}\text{C}$		16			
Reverse Recovery Rise Time	t _b			17		ns	

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$ b. Guaranteed by design, not subject to production testing.

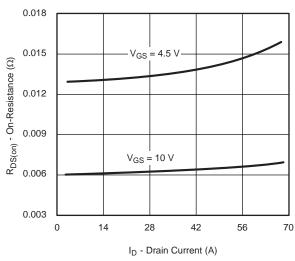
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

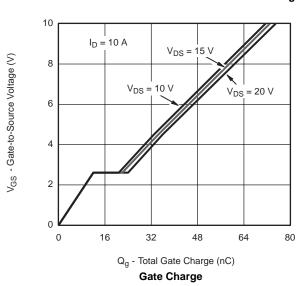


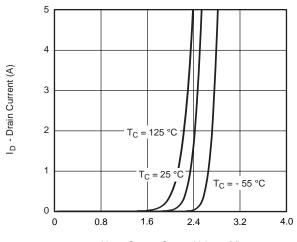
 V_{DS} - Drain-to-Source Voltage (V)

Output Characteristics



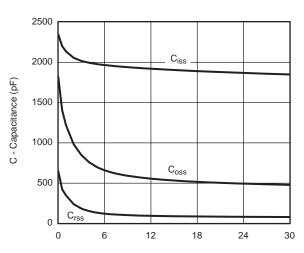
On-Resistance vs. Drain Current and Gate Voltage





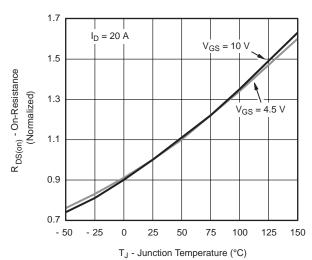
V_{GS} - Gate-to-Source Voltage (V)

Transfer Characteristics



V_{DS} - Drain-to-Source Voltage (V)

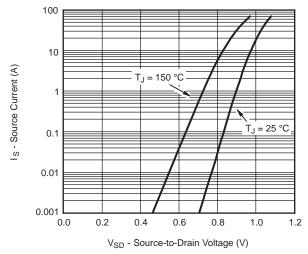
Capacitance



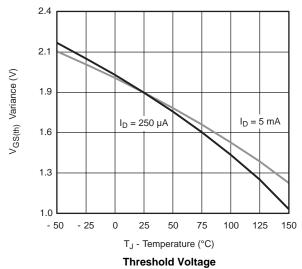
On-Resistance vs. Junction Temperature

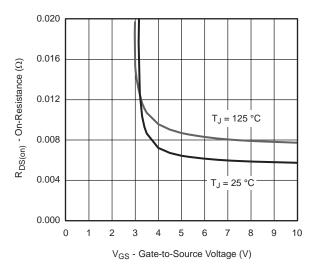


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

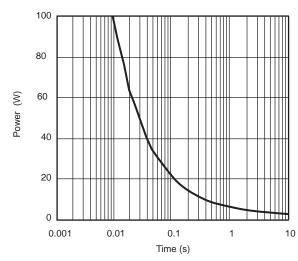


Source-Drain Diode Forward Voltage

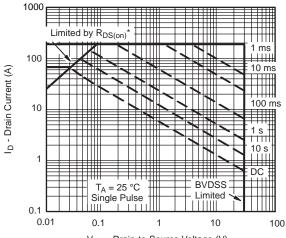




On-Resistance vs. Gate-to-Source Voltage



Single Pulse Power, Junction-to-Ambient



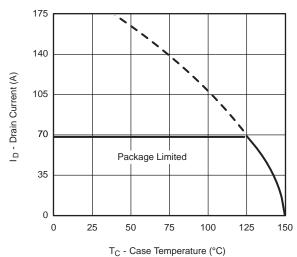
V_{DS} - Drain-to-Source Voltage (V)

Safe Operating Area, Junction-to-Ambient

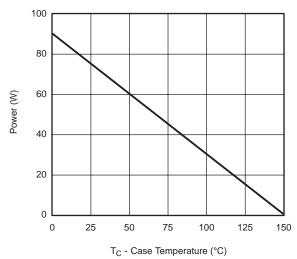
^{*} V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

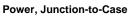


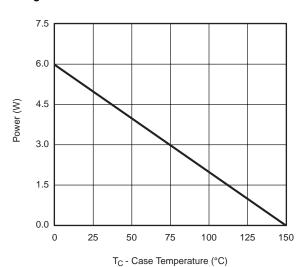
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Current Derating*





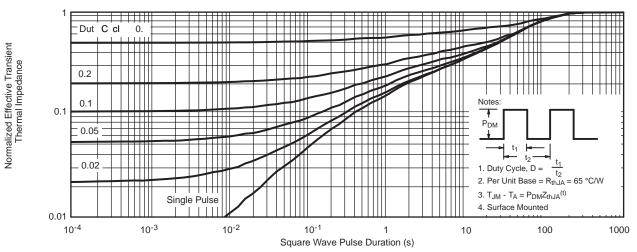


Power, Junction-to-Ambient

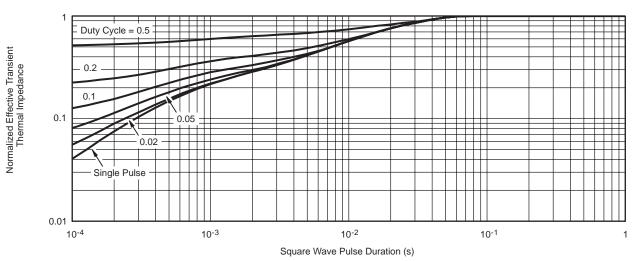
^{*} The power dissipation P_D is based on $T_{J(max)}$ = 150 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package



TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



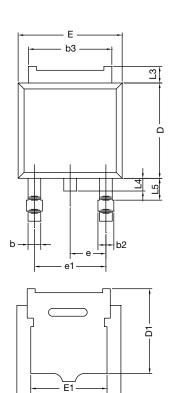
Normalized Thermal Transient Impedance, Junction-to-Ambient

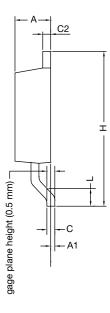


Normalized Thermal Transient Impedance, Junction-to-Case



TO-252AA CASE OUTLINE





	MILLIMETERS		INC	HES	
DIM.	MIN.	MAX.	MIN.	MAX.	
Α	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	5.21	-	0.205	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28 BSC		0.090 BSC		
e1	4.56 BSC		0.180 BSC		
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.14	1.52	0.045	0.060	
FCN: X12-0247-Rev. M. 24-Dec-12					

ECN: X12-0247-Rev. M, 24-Dec-12

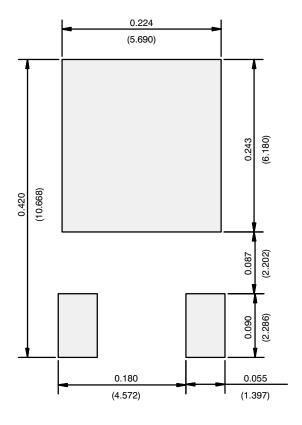
DWG: 5347

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)



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